



TSMC 98-262
Serial Number 09/325,951

#6/BWA Y/2812
7-25-01
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TECHNOLOGY CENTER 2800

AMENDMENT AND RESPONSE TO OFFICE ACTION

FINAL

TO: COMMISSIONER OF PATENTS AND TRADEMARKS
Washington, D. C. 20231

FROM: George O. Saile (Reg. No. 19,572)
20 McIntosh Drive
Poughkeepsie, NY 12603

DATE: 16 July 2001

REF: APPLICANT : Chiang et al.
SERIAL NO. : 09/325,951
ART UNIT : 2812
FILING DATE : 06/04/99
ATT'Y NO. : TSMC 98-262
EXAMINER : R. Pompey
TITLE : Method for Forming High Purity Silicon Oxide Field
Oxide Isolation Region

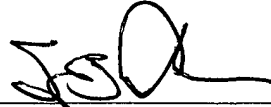
Sir:

In response to an office action mailed on 22 May 2001, please consider the following amendments and remarks pertaining to the above referenced application.

CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service as First Class mail in an envelope addressed to the Commissioner of Patents and Trademarks, Washington, D. C. 20231 on 20 July 2001

Stephen B. Ackerman
Name Reg # 37,761


Signature

7/20/01
Date